Absorptive SPDT Solid State RF Switch

ZFSWA2-63DR+

The Big Deal

- Wide bandwidth 500 to 6000 MHz
- Very high isolation, 65 dB at 1GHz
- Very fast switching, 35ns
- Rugged case with internal hermetically sealed ceramic semi-conductor module



Pricing: \$69.95 (QTY 1-9)

Product Overview

The ZFSWA2-63DR+ is a great general purpose SPDT solid state absorptive RF switch. With its broad frequency range, fast 35 ns switching time and excellent RF performance, the ZFSWA2-63DR+ is an excellent choice for many applications. In addition to it's versatility within system block diagrams, the ZFSWA2-63DR+ is designed for easy integration into your prototype design applications.

Key Features

Feature	Advantages
Designed for any environment	The ZFSWA2-63DR+ is equipped with a rugged shielded case, a hermetically sealed internal device with a wide operating temperature range (-55°C to 100°C)
	Suitable for many environments and applications the ZFSWA2-63DR+ offers excellent performance and value
Integrated CMOS Driver	-Operates from 3-5V -Low control current 5 µA allows compatibility with a variety of driver circuits -Internal Decoupling -Fast 35 ns Switching time
Excellent for a Variety of Applications From Bench to Integrated Systems	-High speed testers -Automated switching networks -Wireless Infrastructure -Military
Excellent RF Performance	-Wide bandwidth: 500 to 6000 MHz -Low Insertion Loss: 1.4 dB Typ -Low Supply current: 18 μA Typ -High Isolation: 65 dB Typ @ 1 GHz



For detailed performance specific

ISO 9001 ISO 14001 AS 9100 CERTIFIED
P.O. Box 350166, Brooklyn, New York 11235-0003 (718) 934-4500 Fax (718) 332-4661 The Design Engineers Search Engine

Provides ACTUAL Data Instantly at minicipouits.com

IF/RF MICROWAVE COMPONENTS

SPDT RF Switch

50Ω 500-6000 MHz

Absorptive RF Switch with Internal Driver Single Supply Voltage, +3V to +5V

Product Features

- Wide bandwidth, 500 to 6000 MHz
- High Isolation, 65 dB typ. at 1 GHz
- Low Insertion loss, 1.4 dB typ.
- Internal CMOS driver
- Fast switching, Rise/fall time, 25 ns typ.
- · Built rugged for tough environments
- Wide operating temperature, -55°C to 100°C

Typical Applications

- Cellular
- ISM, WCDMA, WIMAX
- PCN
- · Automated switching networks
- Military



CASE STYLE: ZZ1322

Connectors	Model	Price	Qty.
SMA	ZFSWA2-63DR+	\$69.95 ea.	(1-9)
BRACKET	(OPTION "B")	\$2.50	(1+)

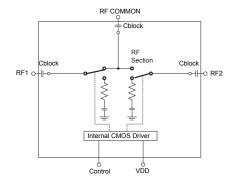
+ RoHS compliant in accordance with EU Directive (2002/95/EC)

The +Suffix has been added in order to identify RoHS Compliance. See our web site for RoHS Compliance methodologies and qualifications.

General Description

The ZFSWA2-63DR+ is a 50Ω high isolation, absorptive SPDT RF switch designed for wireless applications, covering a broad frequency range from 500 to 6000 MHz with low insertion loss. The ZFSWA2-63DR+ operates on a single supply voltage in the range of +3V to +5V. This unit includes an internal CMOS driver. The switch consumes very low supply current, 18 μ A typ. The ZFSWA2-63DR+ switch comes in a rugged built case for tough environments.

Schematic and Application Circuit



Mini-Circuits
ISO 9001 ISO 14001 AS 9100 CERTIFIED

For detailed performance specs

ISO 9001 ISO 14001 AS 9100 CERTIFIED
P.O. Box 350166, Brooklyn, New York 11235-0003 (718) 934-4500 Fax (718) 332-4661 The Design Engineers Search Engine

Provides ACTUAL Data Instantly at minicipality.com



RF Electrical Specifications, 500 - 6000 MHz, T_{AMB} =25°C, V_{DD} = +3V to +5V

Parameter	Condition	Min.	Тур.	Max.	Units	
Frequency Range		500		6000	MHz	
	500 MHz		1.0	1.3		
	1000 MHz		1.15	1.5		
Insertion Loss	2000 MHz		1.4	1.7	dB	
	4000 MHz		1.7	2.1		
	6000 MHz		2.0	2.4		
	500 to 2000 MHz	55	65			
Isolation between Common port and RF1/RF2 Ports	2000 to 4000 MHz	48	57		dB	
	4000 to 6000 MHz	35 50	45			
Isolation between RF1 and RF2 ports	500 to 2000 MHz 2000 to 4000 MHz	43	60 50		dB	
isolation between hir i and hir 2 ports	4000 to 6000 MHz	35	45		ub	
	500 to 2000 MHz		20			
Return Loss (ON STATE)	2000 to 4000 MHz		17		dB	
, ,	4000 to 6000 MHz		15			
	500 to 2000 MHz		13			
Return Loss @ RF1/RF2 ports (OFF STATE)	2000 to 4000 MHz		13		dB	
	4000 to 6000 MHz		13			
	V _{DD} =3V, 500 to 2000		47			
Input IP3	2000 to 6000		40		dBm	
•	V _{DD} =5V, 500 to 2000		49			
	2000 to 6000		44			
	V _{DD} =3V, 500 to 2000 2000 to 6000		24			
Input 1dB Compression (1)	V _{DD} =5V, 500 to 2000		24 30		dBm	
	2000 to 6000		27			
DC.	Electrical Specificat	tions				
		3			V	
VDD, Supply Voltage	V 5V	<u> </u>	10	5		
Supply Current (2)	V _{DD} =5V		18		μΑ	
Control Voltage Low		0		0.5	V	
Control Voltage High (3)		2.7		V _{DD}	V	
Control Current			5		μΑ	
Sw	vitching Specification	ons				
Rise/Fall Time (10 to 90% or 90 to 10% RF)	V _{DD} =5V		25		nSec	
Switching Time (50% CTRL to 90/10% RF)	V _{DD} =5V		35		nSec	
Video Feed through (Control 0-5V, Frequency 1 MHz)	V _{DD} =5V		30		mV _{p-p}	

Notes:



For detailed performance specs & shopping online see web site

^{1.} Note absolute maximum rating for input and dissipated power. At 5V, over 2000-6000 MHz, 0.2 dB compression.

^{2.} Increases with switching repetition rate. See graph.

^{3.} CMOS interface latch-up condition may occur when logic high signal is applied prior to power supply.

Absolute Maximum Ratings

<u> </u>		
Parameter	Ratings	
Operating Temperature	-55°C to 100°C	
Storage Temperature	-55°C to 100°C	
V _{DD} , Supply Voltage	2.7 to 5.5V	
Voltage Control	-0.2V Min. V _{DD} Max.	
RF input power	1Watt	
Dissipated Power at 25°C	370mW	
ESD, HBM	Class 1A (250 to <500V) per JESD22-A114	
ESD, MM	Class A (passes 50V) per JESD22-A115	
ESD, CDM	Class III (500 to <1000V) per JESD22-C101	

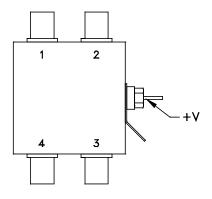
Truth Table (State of control voltage selects the desired switch state)

State of Control Voltage	Switch State - RF Common to		
	RF1	RF2	
Low	ON	OFF	
High	OFF	ON	
ON- low insertion loss state OFF- Isolation State			

Coaxial Connections

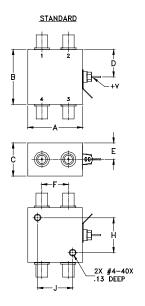
Function	Port Number	Description
RF COM	1	RF Common/ SUM Port
RF1	4	RF Out #1/In Port #1
RF2	3	RF Out #2/In Port #2
Control	2	CMOS Control IN
VDD	V+	Supply Voltage
GND	Case	RF Ground

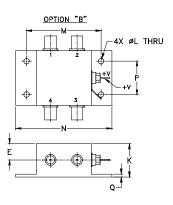
Coaxial Configuration



For detailed performance specs & shopping online see web site

Outline Drawing (ZZ1322)





Outline Dimensions (inch)

В С D Ε F Н K O J L M Ν wt 0.6 -- 0.800 0.800 0.76 0.125 1.688 2.18 0.75 0.07 grams 31.75 31.75 19.05 16.00 9.65 15.24 -- 20.32 20.32 19.30 3.18 42.88 55.37 19.05

Additional Detailed Technical Information

Additional information is available on our web site. To access this information enter the model number on our web site home page.

Performance data, graphs

Case Style: ZZ1322

Environmental Ratings: ENV28

Pricing & Availability Information



For detailed performance specs & shopping online see web site

ISO 9001 ISO 14001 AS 9100 CERTIFIED
P.O. Box 350166, Brooklyn, New York 11235-0003 (718) 934-4500 Fax (718) 332-4661 The Design Engineers Search Engine

IF/RF MICROWAVE COMPONENTS

Provides ACTUAL Data Instantly at minicipcuits.com